

Low-voltage variable capacitance diode

FEATURES

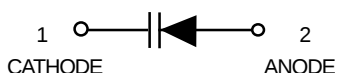
- Ultra small plastic SMD package
- C4: 2.75 pF; ratio: 2.4
- Low series resistance.

APPLICATIONS

- Voltage controlled oscillators (VCO).

DESCRIPTION

The BB145B is a planar technology variable capacitance diode in a SOD523 (SC-79) package.



BB 145B



SOD523 SC-79

MARKING CODE:Z



LIMITING VALUES In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		—	6	V
V_{RM}	peak reverse voltage	in series with a 10 k Ω resistor	—	8	V
I_F	continuous forward current		—	20	mA
T_{stg}	storage temperature		–55	+150	°C
T_j	operating junction temperature		–55	+150	°C

ELECTRICAL CHARACTERISTICS $T_j=25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_R	reverse current	$V_R = 6\text{ V}$; see Fig.2	—	10	nA
		$V_R = 6\text{ V}$; $T_j = 85^\circ\text{C}$; see Fig.2	—	200	nA
r_s	diode series resistance	$f = 470\text{ MHz}$; $V_R = 1\text{ V}$	—	0.6	Ω
C_d	diode capacitance	$V_R = 1\text{ V}$; $f = 1\text{ MHz}$; see Figs 1 and 3	6.4	7.2	pF
		$V_R = 4\text{ V}$; $f = 1\text{ MHz}$; see Figs 1 and 3	2.55	2.95	pF
$\frac{C_d(1V)}{C_d(4V)}$	capacitance ratio	$f = 1\text{ MHz}$	2.2	—	

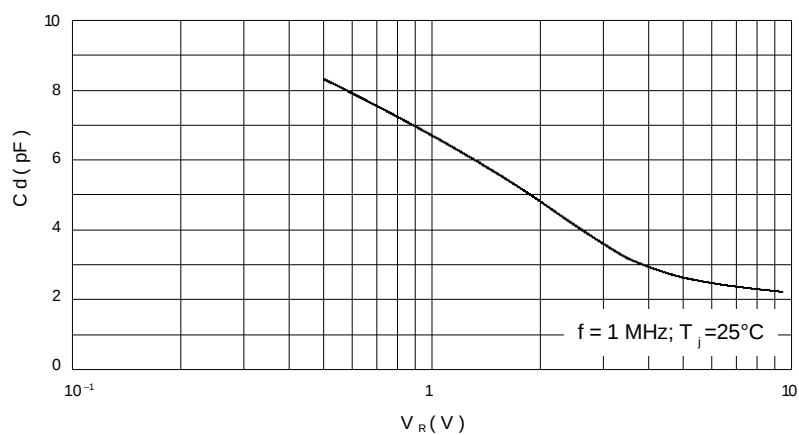
BB 145B


Fig.1 Diode capacitance as a function of reverse voltage; typical values.

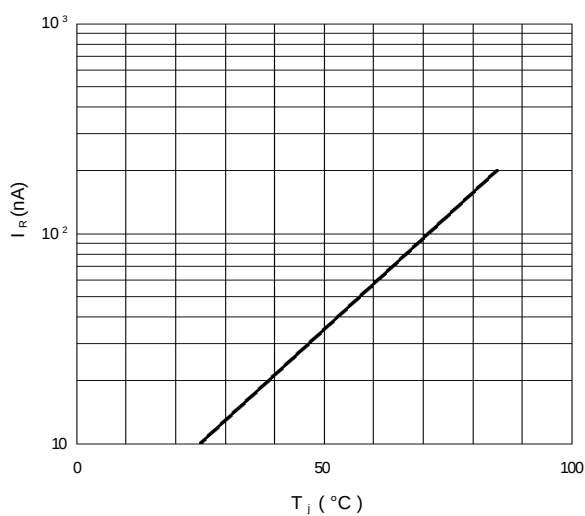


Fig.2 Reverse current as a function of junction temperature; maximum values.

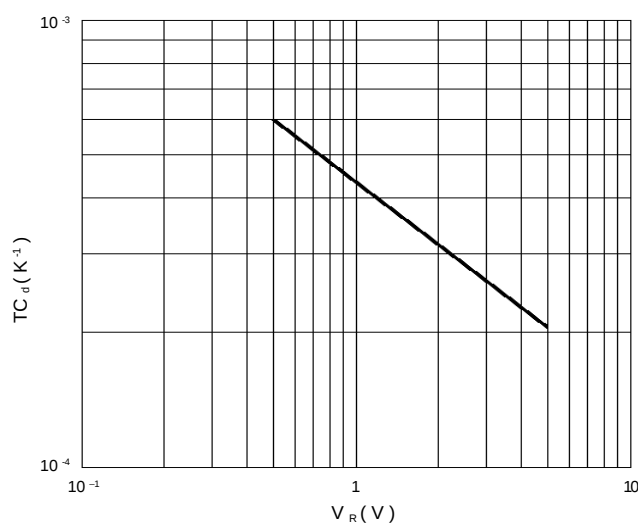


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.